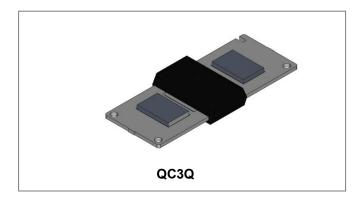


GF3045TS-1 Power Modules Schottky Rectifier



Mechanical Data

- Case: QC3Q
- High temperature soldering guaranteed
 Heated-tool welding 260℃,10 seconds
- Marking Code: GF3045TS-1

Features

- Low thermal resistance
- Lower forward voltage drop, low power loss
- Isolate Package design, ideal for heat dispersion
- High forward current capability
- Trench MOS Schottky technology
- · Excellent anti-humidity
- Low profile package
- High forward surge capability
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V	
Average Rectified Forward Current	I _{F (AV)}	Tc=125°C, In DC	30	Α	
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T _J = 25 °C	350	Α	
Rating for fusing (t<8.3ms)	l²t	T _J = 25 °C	500	A ² sec	

Electrical Characteristics

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 30A, Pulse, T _J = 25 °C	0.49	0.55	V
Reverse Current*	I_{R1} @ V_R = rated V_R T_J = 25 °C		0.02	0.20	mA
	I _{R2}	@V _R = rated V _R T _J = 100 °C	-	20	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	3680	-	pF

Pulse width < 300 μs, duty cycle < 2%

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Thermal-Mechanical Specifications

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	IN DC Forward Mode, without reverse bias, t ≤1 h	-55 to +200	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	-	1.5	°C/W

Ratings and Characteristics Curves

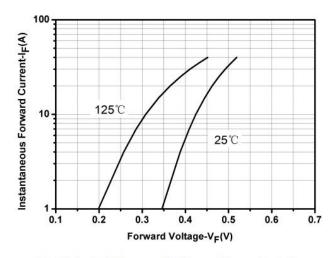


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics

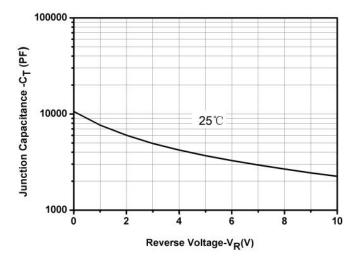


Fig.3-Capacitance vs. Reverse Voltage

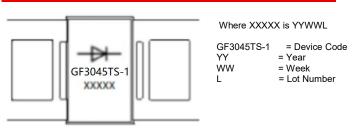
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Ordering Information

Device	Package	Shipping
GF3045TS-1	QC3Q	32pcs/Tube

Marking Diagram



	/N Terminals	Additional
	-1-S1 Tin Plated	None
	-1-S2 Tin Plated	Solder Paste
	-1-S3 Tin Plated	Solder Block
	-1-N1 Nickel Plated	None
	-1-N2 Nickel Plated	Solder Paste
,	-1-N3 Nickel Plated	Solder Block



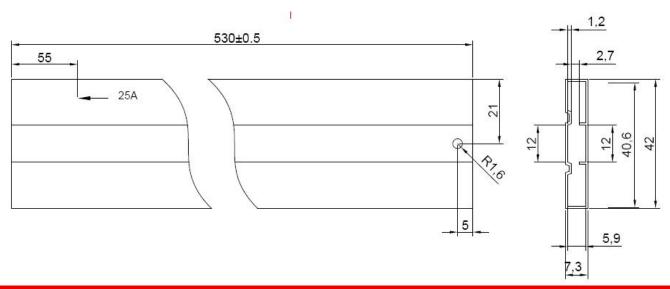


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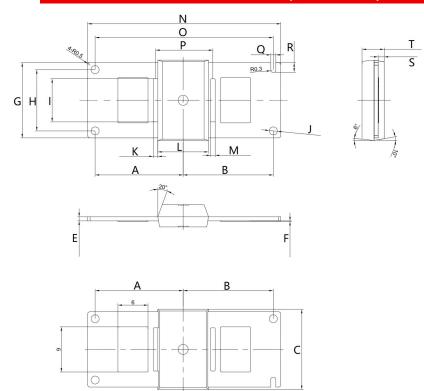
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Tube Specification QC3Q (Millimeters)



Mechanical Dimensions QC3Q (Millimeters)



Symbol	Dimensions in millimeters			
	Min.	Typical	Max	
Α		17.54		
В		17.96		
С	15.90	16.00	16.10	
E	0.77	0.80	0.83	
F	0.08	0.10	0.12	
G	14.90	15.00	15.10	
Н	12.15	12.20	12.25	
I	8.55	8.60	8.65	
J		1.60	1.70	
K	0.86	0.90	0.93	
L	10.00	10.10	10.20	
М	0.87	0.90	0.93	
N	38.40	38.50	38.60	
0	35.45	35.50	35.55	
Р	11.32	11.42	11.52	
Q		1.00	1.10	
R		1.90	2.00	
S	1.15	1.20	1.25	
T	4.30	4.40	4.50	

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